NSN 5961-01-386-6173

Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-386-6173 **Inclosure Material:**

Metal

Overall Length:

0.150 inches

Semiconductor Material:

Gallium phosphide

Special Features:

Light output is 0.6 to 0.8 microlamberts at 520 nanometers

Nuclear Hardness Critical Feature:

Hardened

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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